NSN 5962-01-135-2101

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Body	/ Length:
1.310) inches
Body	/ Width:
0.600) inches
Body	/ Height:
0.052	2 inches
Maxi	mum Power Dissipation Rating:
400.0) milliwatts
Oper	ating Tempurature Range:
+0.0/	+75.0 degrees celsius
Stora	age Tempurature Range:
-65.0	/+150.0 degrees celsius
End	Application:
Train	ing dev 08783
Featu	ures Provided:
Herm	etically sealed and programmable and expandable and wire-or outputs and w/enable
Inclo	sure Material:
Cera	mic and glass
Inclo	sure Configuration:
Dual-	in-line
Outp	ut Logic Form:
Trans	sistor-transistor logic
Input	Circuit Pattern:
8 inp	ut
Term	inal Surface Treatment:
Solde	
Volta	ge Rating And Type Per Characteristic:
-1.5 \	volts power source and 5.5 volts power source
Time	Rating Per Chacteristic:
75.00) nanoseconds propagation delay time, low to high level output
Mem	ory Device Type:
Rom	
Mem	ory Capacity:
Unkn	own
Term	inal Type And Quantity:
24 pr	inted circuit
Shelf	Life:
N/a	
Unit	Of Measure:
Demi	litarization:
Yes -	demil/mli

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